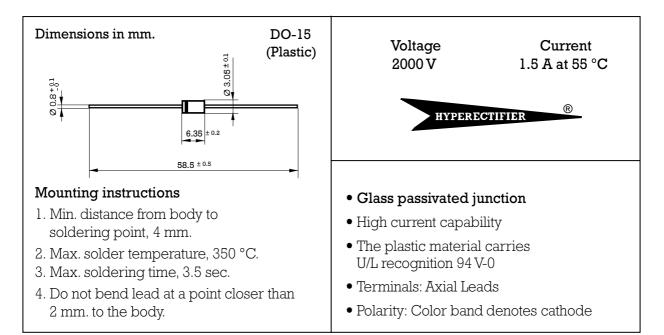


1.5 Amp. Glass Passivated Fast Diode



Maximum Ratings, according to IEC publication No. 134

		RGP 15-20
V _{RRM}	Peak recurrent reverse voltage	2000 V
I _{F(AV)}	Forward current at Tamb = 55 °C	1.5 A
I _{FRM}	Recurrent peak forward current	6 A
$I_{\rm FSM}$	8.3 ms. peak forward surge current	20 A
t _{rr}	$ \begin{array}{l} \text{Max. reverse recovery} \\ \text{time from} \end{array} \begin{array}{l} I_{\text{F}} = 0.5 \text{ A} \\ I_{\text{R}} = 1 \text{ A} \\ I_{\text{RR}} = 0.25 \text{ A} \end{array} $	300 ns
C _j	Typical Junction Capacitance at 1 MHz and reverse voltage of $4V_{\mbox{\tiny DC}}$	5 pF
Tj	Operating temperature range	– 65 to + 175 °C
T _{stg}	Storage temperature range	– 65 to + 175 °C

Electrical Characteristics at Tamb = 25 °C

V _F	Max. forward voltage drop at $I_F = 1.5 P$	3 V
I _R	Max. reverse current at V_{RRM} at 25 °C at 150 °C	5 µ A 50 µ A
R _{thj-a}	Max. thermal resistance (I = 10 mm.)	30 °C/W

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